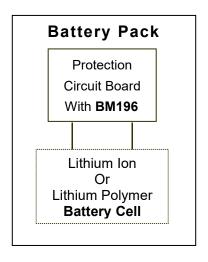


One-Cell Li Battery Protectors

General Description

The BM196-VCBD-DE-A is protector for lithium-ion and lithium polymer rechargeable battery with high accuracy voltage detection. It can be used for protecting single cell lithium-ion or/and lithium polymer battery packs from overcharge, overdischarge, overcurrent and short circuit. The IC has suitable protection delay functions and low power consumption property.

Applications



Features

- Overcharge Detection Voltage
 - Typ.4.425V

■ Accuracy ±20mV (Ta=25°C)

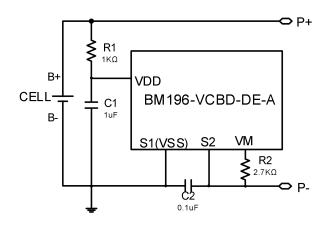
±50mV (Ta=-40°C~85°C)

- Overdischarge Detection Voltage
 - Typ.2.500V
 - Accuracy ±70mV (Ta=25°C)
- Discharge Overcurrent Detection Voltage
 - Typ.0.075V ($V_{DD} = 3.300V$)
 - Accuracy ±10mV (Ta=25°C)
- Short Circuit Detection Voltage
 - Typ. $0.550V (V_{DD} = 3.300V)$
 - Accuracy ±100mV (Ta=25°C)
- Low Current Consumption
 - Standard working current

Typ. 2.5uA (V_{DD} = 3.900V, Ta=25 $^{\circ}$ C)

- With auto wake up
 - Typ. 0.8uA ($V_{DD} = 2.000V$, $Ta=25^{\circ}C$)
- 0V charge function is allowed
- Auto Wake up function is allowed
- Small Package
 - DFNWB2.1*4.1-4L
- FET general characteristics
 - V_{DS}=20V
 - R_{SS(ON)}=10 m Ω (V_{GS}=3.9V,I_D=1A)
 - ESD Rating: 2000V HBM

Typical Application Circuits



Notes

 R_1 and C_1 are to stabilize the supply voltage of the BM196-VCBD-DE-A. $R_1\,C_1$ is hence regarded as the time constant for V_{DD} pin. R_1 and R_2 can also be a part of current limit circuit for the BM196-VCBD-DE. Recommended values of these elements are as follows:

- 0.3kΩ < R₁ < 1.5KΩ. A larger value of R₁ results in higher detection voltage, introducing errors.
- 1.5k Ω < R₂ < 4K Ω . A larger value of R₂ possibly prevents resetting from overdischarge even with a charger.
- R₁+ R₂ > 1.6KΩ. Smaller values may lead to power consumption over the maximum dissipation rating of the BM196-VCBD-DE-A.

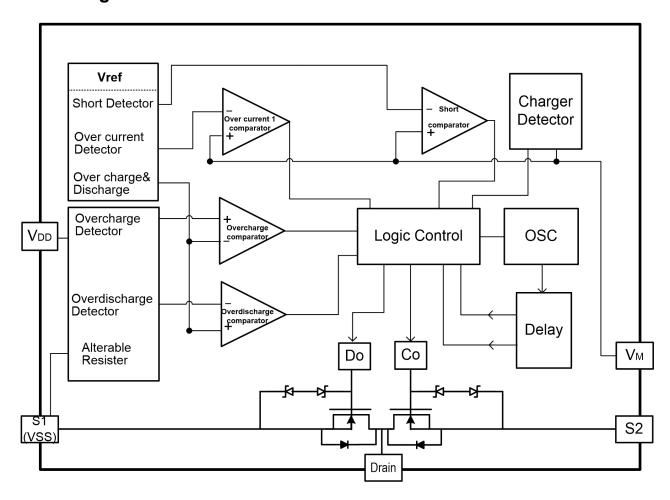
The requirement or resistors and capacitors and the value of constants should be decided depending upon the system function and characteristics.



Marking contents

Symbol	Meaning	Top View
196	Series Name	P1 → 🔘
VCBD-A	Product Name	196VCBD-A YW
YW	Lot Number	

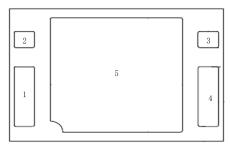
Block Diagram





Pin Description





Top View

Bottom View

Pin	Symbol	Description
P1	S1	The source terminal of MOSFET switch for discharge control(Same as VSS)
P2	VDD	Power supply
P3	VM	Connected to charger's negative pin
P4	S2	The source terminal of MOSFET switch for charge control
P5	Drain	The common drain terminal of MOS, it should be floating



Electrical Characteristics

(Ta=25°C unless otherwise specified)

Symbol	Item	Conditions	Min.	Тур.	Max.	Unit	
DETECTION VOLTAGE AND DELAY TIME							
Vdet1	Overcharge Detection Voltage	-	4.405	4.425	4.445	V	
Vrel1	Release Voltage For Overcharge Detection	-	4.185	4.225	4.265	V	
Vdet2	Overdischarge Detection Voltage	-	2.430	2.500	2.570	V	
Vrel2	Release Voltage For Overdischarge	-	2.810	2.900	2.990	V	
Vdet3	Discharge Overcurrent Detection Voltage	V _{DD} = 3.300V	0.065	0.075	0.085	V	
Vshort	Short Protection Voltage	V _{DD} = 3.300V	0.450	0.550	0.650	V	
Vcha	Charger Detection (Charge Overcurrent)		-0.085	-0.075	-0.065	V	
Vriov	Discharge Overcurrent Release Voltage		0.65* VDD	0.80* VDD	0.95* VDD	V	
V0cha	0V Battery Charge Starting Charger Voltage	Applied for 0V battery charge function	1.2	-	-	V	
Vdet5	Charger Overvoltage Detection Voltage	V _{DD} = 3.600V	6	8	10	V	
Vrel5	Release Voltage for Charger Overvoltage	V _{DD} = 3.600V	5.5	7.5	9.5	V	
Tvdet1	Overcharge Detection Delay Time	V _{DD} = 4.0V→4.5V	700	1000	1300	ms	
Tvrel1	Overcharge Release Delay Time	V _{DD} = 4.5V→4.0V	9	16	30	ms	
Treset	Overcharge Reset Delay Time	V _{DD} = 4.5V→4.0V→4.5V	7	14	28	ms	
Tvdet2	Overdischarge Detection Delay Time	V _{DD} = 4.0V→2.0V	67.2	96.0	124.8	ms	
Tvrel2	Overdischarge Release Delay Time	$V_{DD} = 2.0V \rightarrow 3.0V, V_{M} = 0V$	1.4	2.0	2.6	ms	
Tvdet3	Discharge Overcurrent Detection Delay Time	$V_{DD} = 3.3V, V_{M} = 0V \rightarrow 0.2V$	8.4	12.0	15.6	ms	
Tab	Charge Overcurrent Detection Delay Time	$V_{DD} = 3.3V, V_{M} = 0V \rightarrow -0.2V$	5.6	8.0	10.4	ms	
Tshort	Short Detection Delay Time	$V_{DD} = 3.3V, V_{M} = 0V \rightarrow 1.2V$	250	500	750	us	
Tvrel3	Discharge Overcurrent Release Delay Time	V_{DD} =3.3V, V_{M} = 0.2V \to 0 V	1.4	2.0	2.6	ms	
OUTPUT	VOLTAGE AND V _M INTERNAL RESISTANCE						
R _{VMD}	Resistance between V_{M} and V_{DD}	$V_{DD}=2.0V, V_{M}=0V$	300	600	900	kΩ	
R _{VMS}	Resistance between V_{M} and V_{SS}	V_{DD} =3.4 V , V_{M} =1 V	25	50	100	kΩ	
OPERRA ⁻	OPERRATION VOLTAGE AND CURRENT CONSUMPTION						
V_{DD}	Operating Input Voltage	V _{DD} -Vss	1.6	V _{DD}	8.0	V	
V _M	Operating Input Voltage	V_{DD} - V_{M}	1.5	-	28.0	V	
I _{DD}	Supply Current	$V_{DD} = 3.9V, V_{M} = 0V$	-	2.5	5.0	uA	
I _{STANDBY}	Standby Current (for products with Auto wake up)	$V_{DD} = 2.0V, V_{M} = 0V \rightarrow 2.0V$	-	0.8	2.0	uA	



Electrical Characteristics 1*

(Ta=-5~55°C unless otherwise specified)

Symbol	Item	Conditions	Min.	Тур.	Max.	Unit
DETECTIO	ON VOLTAGE AND DELAY TIME					
Vdet1	Overcharge Detection Voltage	-	4.390	4.425	4.460	V
Vrel1	Release Voltage For Overcharge Detection	-	4.165	4.225	4.285	V
Vdet2	Overdischarge Detection Voltage	-	2.410	2.500	2.590	V
Vrel2	Release Voltage For Overdischarge	-	2.810	2.900	2.990	V
Vdet3	Discharge Overcurrent Detection Voltage	V _{DD} = 3.300V	0.060	0.075	0.090	V
Vshort	Short Protection Voltage	V _{DD} = 3.300V	0.400	0.550	0.700	V
Vcha	Charger Detection (Charge Overcurrent)	-	-0.090	-0.075	-0.060	V
Vriov	Discharge Overcurrent Release Voltage	-	0.65* VDD	0.80* VDD	0.95* VDD	V
V0cha	0V Battery Charge Starting Charger Voltage	Applied for 0V battery charge function	1.2	-	-	V
Vdet5	Charger Overvoltage Detection Voltage	V _{DD} = 3.600V	6	8	11	V
Vrel5	Release Voltage for Charger Overvoltage	V _{DD} = 3.600V	5.5	7.5	10.5	V
Tvdet1	Overcharge Detection Delay Time	V _{DD} = 4.0V→4.5V	650	1000	1350	ms
Tvrel1	Overcharge Release Delay Time	V _{DD} = 4.5V→4.0V	8	16	31	ms
Treset	Overcharge Reset Delay Time	V _{DD} = 4.5V→4.0V→4.5V	6	14	29	ms
Tvdet2	Overdischarge Detection Delay Time	V _{DD} = 4.0V→2.0V	62.4	96.0	129.6	ms
Tvrel2	Overdischarge Release Delay Time	$V_{DD} = 2.0V \rightarrow 3.0V, V_{M} = 0V$	1.3	2.0	2.7	ms
Tvdet3	Discharge Overcurrent Detection Delay Time	$V_{DD} = 3.3V, V_{M} = 0V \rightarrow 0.2V$	7.8	12.0	16.2	ms
Tab	Charge Overcurrent Detection Delay Time	$V_{DD} = 3.3V, V_{M} = 0V \rightarrow -0.2V$	5.2	8.0	10.8	ms
Tshort	Short Detection Delay Time	$V_{DD} = 3.3V, V_{M} = 0V \rightarrow 1.2V$	200	500	800	us
Tvrel3	Discharge Overcurrent Release Delay Time	$V_{DD} = 3.3V, V_{M} = 0.2V \rightarrow 0 V$	1.3	2.0	2.7	ms
OUTPUT \	OLTAGE AND V _M INTERNAL RESISTANCE					
R_{VMD}	Resistance between V _M and V _{DD}	V _{DD} =2.0V, V _M =0V	150	600	2100	kΩ
R_{VMS}	Resistance between V _M and V _{SS}	$V_{DD}=3.4V, V_{M}=1V$	12	50	150	kΩ
OPERRAT	ION VOLTAGE AND CURRENT CONSUMPTION	ON				
V_{DD}	Operating Input Voltage	V _{DD} -Vss	1.6	V _{DD}	8.0	V
V _M	Operating Input Voltage	V_{DD} - V_{M}	1.5	-	28.0	V
I _{DD}	Supply Current	$V_{DD} = 3.9V, V_{M} = 0V$	-	2.5	5.5	uA
I _{STANDBY}	Standby Current (for products with Auto wake up)	V _{DD} = 2.0V, V _M =0V→2.0V	-	0.8	2.8	uA

^{1*} The Electrical parameters for this temperature range is guaranteed by design, not tested in production.



Electrical Characteristics 1*

(Ta =-40°C~85°C unless otherwise specified)

Symbol	Item	Conditions	Min.	Тур.	Max.	Unit	
DETECTION VOLTAGE AND DELAY TIME							
Vdet1	Overcharge Detection Voltage	-	4.375	4.425	4.475	V	
Vrel1	Release Voltage For Overcharge Detection	-	4.155	4.225	4.295	V	
Vdet2	Overdischarge Detection Voltage	-	2.400	2.500	2.600	V	
Vrel2	Release Voltage For Overdischarge	-	2.800	2.900	3.000	V	
Vdet3	Discharge Overcurrent Detection Voltage	V _{DD} = 3.300V	0.055	0.075	0.095	V	
Vshort	Short Protection Voltage	V _{DD} = 3.300V	0.350	0.550	0.750	V	
Vcha	Charger Detection (Charge Overcurrent)	-	-0.095	-0.075	-0.055	V	
Vriov	Discharge Overcurrent Release Voltage	-	0.65* VDD	0.80* VDD	0.95* VDD	V	
V0cha	0V Battery Charge Starting Charger Voltage	Applied for 0V battery charge function	1.2	-	-	V	
Vdet5	Charger Overvoltage Detection Voltage	V _{DD} = 3.600V	5.5	8	12.0	V	
Vrel5	Release Voltage for Charger Overvoltage	V _{DD} = 3.600V	5.0	7.5	11.5	V	
Tvdet1	Overcharge Detection Delay Time	V _{DD} = 4.0V→4.5V	500	1000	1500	ms	
Tvrel1	Overcharge Release Delay Time	V _{DD} = 4.5V→4.0V	7	16	32	ms	
Treset	Overcharge Reset Delay Time	V _{DD} = 4.5V→4.0V→4.5V	5	14	30	ms	
Tvdet2	Overdischarge Detection Delay Time	V _{DD} = 4.0V→2.0V	48	96.0	144	ms	
Tvrel2	Overdischarge Release Delay Time	$V_{DD} = 2.0V \rightarrow 3.0V, V_{M} = 0V$	1	2.0	3	ms	
Tvdet3	Discharge Overcurrent Detection Delay Time	$V_{DD} = 3.3V, V_{M} = 0V \rightarrow 0.2V$	6	12.0	18	ms	
Tab	Charge Overcurrent Detection Delay Time	$V_{DD} = 3.3V, V_{M} = 0V \rightarrow -0.2V$	4	8.0	12	ms	
Tshort	Short Detection Delay Time	$V_{DD} = 3.3V, V_{M} = 0V \rightarrow 1.2V$	150	500	850	us	
Tvrel3	Discharge Overcurrent Release Delay Time	$V_{DD} = 3.3V, V_{M} = 0.2V \rightarrow 0 V$	1	2.0	3	ms	
OUTPUT \	/OLTAGE AND V _M INTERNAL RESISTANCE						
R_{VMD}	Resistance between V _M and V _{DD}	$V_{DD}=2.0V, V_{M}=0V$	150	600	2100	kΩ	
R _{VMS}	Resistance between V _M and V _{SS}	$V_{DD}=3.4V, V_{M}=1V$	12	50	150	kΩ	
OPERRAT	ION VOLTAGE AND CURRENT CONSUMPTION	ON					
V_{DD}	Operating Input Voltage	V _{DD} -Vss	1.6	V _{DD}	8.0	V	
V _M	Operating Input Voltage	V_{DD} - V_{M}	1.5	-	28.0	V	
I _{DD}	Supply Current	$V_{DD} = 3.9V, V_{M} = 0V$	-	2.5	6.0	uA	
I _{STANDBY}	Standby Current (for products with Auto wake up)	$V_{DD} = 2.0V, V_{M} = 0V \rightarrow 2.0V$	-	0.8	3.0	uA	

^{1*} The Electrical parameters for this temperature range is guaranteed by design, not tested in production.



Electrical Characteristics

(Ta=25°C,GND=0V unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Drain-source Breakdown Voltage	BVDSS	ID=250uA,VGS=0V	20	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS =16V, VGS =0V	-	-	1	uA
Gate-body Leakage Current	IGSS	VGS=±10V,VDS=0V	-	-	±10	uA
Gate-source Breakdown Voltage	BVGS	IG=250uA,VDS=0V	±10	-	-	V
Gate Threshold Voltage	VGS(th)	VDS=VGS, ID=250uA	0.5	0.8	1.1	V
	RSS(on)	VGS=4.2V,ID=2A	6.7	9.7	13.7	
		VGS=3.9V, ID=2A	7	10	14	
Static Source-Source On		VGS=3.7V, ID=2A	7.2	10.2	14.2	0
Resistance		VGS=3.5V, ID=2A	7.5	10.5	14.5	mΩ
		VGS=3.3V,ID=2A	7.9	10.9	14.9	
		VGS=3.0V, ID=2A	9	12	16	
Forward On Voltage	VSD	VGS=0V,IF=1A	0.4	0.76	1.0	V

Electrical Characteristics 1*

(Ta=25°C,GND=0V,S1=0 unless otherwise specified)

Parameter	Symbol	Test condition	Min.	Тур.	Max.	Unit	Note
	Idet3 1	VDD=4.2V	5.3	7.7	11.1	Α	
Discharge	ldet3 2	VDD=3.9V	5.2	7.5	10.6	А	
Overcurrent	Idet3 3	VDD=3.7V	5.1	7.4	10.4	А	
Detect	Idet3 4	VDD=3.5V	5.0	7.1	10.0	А	
Current	Idet3 5	VDD=3.3V	4.8	6.9	9.5	А	
	Idet3 6	VDD=3.0V	4.5	6.3	8.5	А	Vdet3=0.075V
	Icha 1	VDD=4.2V	5.3	7.7	11.1	А	Vcha=-0.075V
Charge	Icha 2	VDD=3.9V	5.2	7.5	10.6	А	
Overcurrent	Icha 3	VDD=3.7V	5.1	7.4	10.4	А	
Detect	Icha 4	VDD=3.5V	5.0	7.1	10.0	А	
Current	Icha 5	VDD=3.3V	4.8	6.9	9.5	А	
	Icha 6	VDD=3.0V	4.5	6.3	8.5	А	

^{1*} The Electrical parameters for this temperature range is guaranteed by design, not tested in production.



Absolute Maximum Ratings

(Ta=25°C,VSS=0V)

Symbol	Item	Ratings	Unit
V_{DD}	Supply Voltage	-0.3 to 8	V
V_{M}	V _M Pin Input Voltage	V _{DD} -28 to V _{DD} +0.3	٧
V _{GS}	Gate-Source Voltage	±10	V
V _{DS}	Drain- Source Voltage	20	V
ID	Drain Current	10	A
Pd	Power Consumption	150	mW
Та	Operating Temperature Range	-40 to 85	°C
Tstg	Storage Temperature Range	-55 to 125	$^{\circ}$

Caution: These values must not be exceeded under any conditions!



Function Description

Normal Condition:

VDD is between the Overdischarge Detection Voltage (Vdet2) and Overcharge Detection Voltage (Vdet1) and the VM voltage is between Charger Detection Voltage (Vcha) and the Discharge overcurrent Detection Voltage (Vdet3), therefore the MOS-FET of charge and discharge are all on. Charging and discharging can be carried out freely.

Overcharge Condition:

When V_{DD} increases and passes Vdet1 during charging under the normal condition, the charge control FET turns off after Overcharge Detection Delay Time (Tvdet1). If, within Tvdet1, V_{DD} becomes lower than Vdet1 and stays for duration shorter than Overcharge Reset Delay Time (Treset) before rising up over Vdet1 again, this type of instantaneous falling of V_{DD} is ignored. Otherwise, if the time V_{DD} stays lower than Vdet1 is longer than Treset, the timing related to Tvdet1 shall be reset.

Charge Overcurrent Condition:

If the VM voltage falls below the Charger Detection Voltage (Vcha) during charging under normal condition and it continues for the Charge Overcurrent Delay Time (Tvcha) or longer, the charge control FET turns off and charging stops. This action is called the charge overcurrent detection.

Charge overcurrent detection works when the discharging control FET is on and the VM voltage falls below the Charger Detection Voltage (Vcha). To an overdischarged battery, only when charging makes the battery voltage higher than the Overdischarge Detection Voltage (Vdet2), the charge overcurrent detection can act. Charge overcurrent state is released, once the voltage difference between VM and VSS becomes less than the Charge Overcurrent Detection Voltage (Vcha).

Overcharge Protection Release Condition:

The charging state can be reset and charge control FET will turn on, as follow condition:

- (1) When the VM voltage is equal to or higher than Vdet3 (eg.when a charger is disconnected and a load is connected), VDD becomes lower than the Overcharge Detection Voltage (Vdet1), and stays longer than Overcharge Release Delay Time (Tvrel1), the charge control FET turns on.
- (2) When the VM voltage is between Vdet3 and Vcha (usually only be forced intentionally), VDD becomes lower than the Overcharge Release Voltage (Vrel1), and stays longer than Overcharge Release Delay Time (Tvrel1), the charge control FET turns on.
- (3) When the VM voltage is lower than Vcha (eg.when a charger is connected), even if VDD level is lower than Vrel1, the overcharge state will not release and charge control FET keep off until disconnect the charger with the battery pack.

Note1: when a charger is disconnected and a load is connected, the VM voltage is pulled to a value higher than Vdet3. Then IC detects the load-connecting condition.

Note2: when a charger keeps connecting, the VM voltage is equal to the voltage difference between VDD and charger which is lower than Vcha.

Overdischarge Condition:

While discharging, after VDD lowers below Overdischarge Detection Voltage (Vdet2), the discharge control FET turns off after Overdischarge Detection Delay Time (Tvdet2), discharging is stopped.

Overdischarge Protection Release Condition:

When IC is in overdischarge condition, if a charger is connected to the battery pack, and the battery supply voltage becomes higher than Vdet2, the discharge control FET turns on, allowing discharging action.



The discharging state also can be reset and the output of Do becomes high when VDD becomes higher than the Overdischarge Release Voltage (Vrel2), VM is between Vcha and VDD, and stays longer than Release Delay Time (Tvrel2). When a charger is connected from the battery pack, while the VDD level is lower than Vdet2, the battery pack makes charger current allowable through the internal parasitic diode.

Charger Detect Condition:

When a battery in the overdischarge condition is connected to a charger and provided that the VM voltage is lower than the Charger Detection Voltage (Vcha), IC releases the overdischarge condition and turns on the discharge control FET as the battery voltage becomes higher than the Overdischarge Detection Voltage (Vdet2) since the charger detection function works. This action is called charger detection.

When a battery in the overdischarge condition is connected to a charger and provided that the VM pin voltage is between the Charger Detection Voltage (Vcha) and Discharge overcurrent Detection Voltage (Vdet3), IC releases the overdischarge condition when the battery voltage reaches the Overdischarge Release Voltage (Vrel2) or higher.

Discharge Overcurrent Protection:

During discharging, the current varies with load, and VM increases with the rise of the discharging current. Once VM rises up to the Discharge Overcurrent Detection Voltage (Vdet3) or higher and stays longer than the Discharge overcurrent Delay Time (Tvdet3), IC will turn off the discharge control FET. After that Discharge Overcurrent state is removed, i.e. VM <Vriov, and the circuit recovers to normal condition. The current of Discharge Overcurrent protection is related to Vdet3 and the ON resistance of the two FETs (R_{SS (on)}).

Short Circuit Protection:

This function has the same principle as the overcurrent protection. But, the Short Circuit Protection Delay Time (Tshort) is far shorter than Tvdet3, and the Short Protection Detection Voltage (Vshort) is far higher than Vdet3. When the circuit is shorted, VM increases rapidly. Once VM≥Vshort, IC will turn off the discharge control FET. After the short circuit state is removed, i.e. VM < Vriov, the circuit recovers to the normal condition. The short circuit peak current is related to Vshort and the ON resistance of the two FETs (R_{SS (on)}).

0V battery charge function:

This function is used to recharge the connected battery whose voltage is 0V due to the self-discharge. When the 0 V battery charge starting charger voltage (V0cha) or higher is applied between P+ and P- pins (in the Typical Application Circuits of Page1) by connecting a charger, the charge control FET gate is fixed to VDD pin voltage. When the voltage between the gate and source of the charge control FET becomes equal to or higher than the turn-on voltage by the charger voltage, the charge control FET turns on to start charging. At this time, the discharge control FET is off and the charging current flows through the internal parasitic diode in the discharge control FET. When the battery voltage becomes equal to or higher than the Overdischarge Detection Voltage (Vdet2), the IC enters the normal condition.

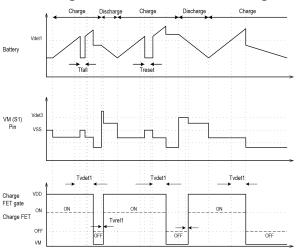
Charger Overvoltage Protection:

During charging, if the voltage of the charger increases and passes Charger Overvoltage Detection Voltage (Vdet5), the output of Co pad will change from high to low, turning off the charging control FET. The output of Co becomes high immediately when the voltage of the charger becomes lower than the Charger Overvoltage Release Voltage (Vrel5).

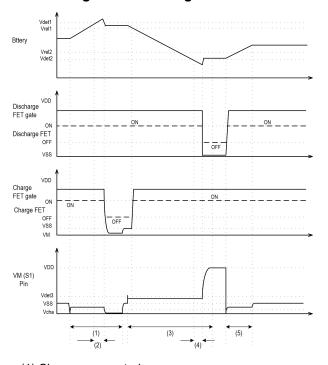


Operation Timing Chart

Operation Timing Chart (1) Overcharge, Timer Reset for Overcharge

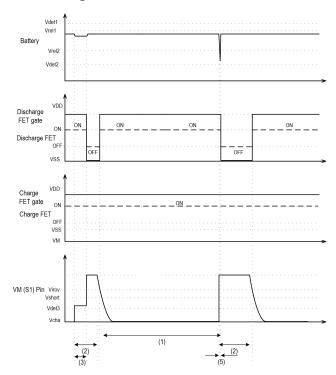


Operation Timing Chart (2) Overcharge/Overdischarge Detection



- (1) Charger connected
- (2) Overcharge Detection Delay Time (Tvdet1)
- (3) Load connected
- (4) Overdischarge Detection Delay Time (Tvdet2)
- (5) Normal charging

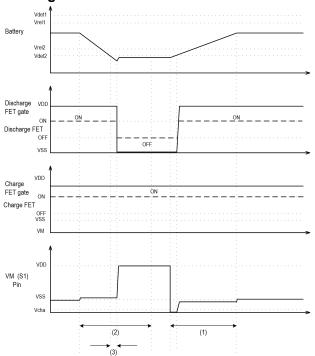
Operation Timing Chart (3) Discharge Overcurrent and Short Protection



- (1) Normal condition
- (2) Load connection
- (3) Discharge Overcurrent Delay Time (Tvdet3)
- (4) Short Circuit Delay Time (Tshort)

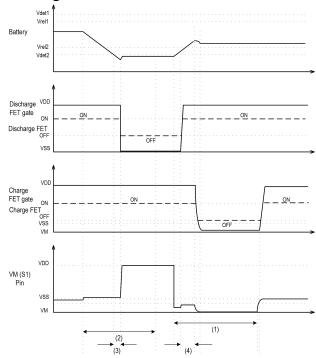


Operation Timing Chart (4) Charger Connection Detection



- (1) Charger connection
- (2) Load connection
- (3) Overdischarge Detection Delay (Tvdet2)

Operation Timing Chart (5) Charge Overcurrent Detection



- (1) Charger connection
- (2) Load connection
- (3) Overdischarge Detection Delay Time (Tvdet2)
- (4) Charge Overcurrent Detection Delay Time



Test Circuits

(1) Overcharge detection voltage and overcharge release voltage (Test circuit 1)

The Overcharge Detection Voltage (Vdet1) is the voltage between V_{DD} and V_{SS} to which when V1 increases and keeps the condition for overcharge delay time, The charging control FET turns off, Vs_1 is the threshold of a diode, The Overcharge Release Voltage (Vrel1) is the voltage between V_{DD} and V_{SS} to which when V1 decreases, The charging control FET turns on, Vs_1 =0V.

(2) Overdischarge detection voltage and Overdischarge release voltage (Test circuit 1)

The Overdischarge Detection Voltage (Vdet2) is the voltage between V_{DD} and V_{SS} to which when V1 decreases and keep the condition for overdischarge delay time, The discharging control FET turns off, $Vs_1=V1$. The overdischarge Release Voltage (Vrel2) is the voltage between V_{DD} and V_{SS} to which when V1 increases, The discharging control FET turns on, $Vs_1=0V$.

(3) Discharge overcurrent detection voltage and short circuit detection voltage (Test circuit 2)

The Discharge overcurrent Detection Voltage (Vdet3) is the voltage between V_M and V_{SS} to which when V_M increases and keep the condition for Discharge overcurrent Delay Time (Tvdet3), The discharging control FET turns off, $Vs_1=V1$. The Short Circuit Detection Voltage (Vshort) is the voltage between V_M and V_{SS} to which when V_M increases and keep the condition for Short Circuit Delay Time (Tshort), The discharging control FET turns off, $Vs_1=V1$.

(4) Charger detection voltage and charge overcurrent detection voltage (Test circuit 2)

In the overdischarge condition, increase V1 gradually until it is between Vdet2 and Vrel2. T The voltage between V_M and V_{SS} to which when V2 decreases, when the discharging control FET turns on, V_{S_1} =0V, is the Charger Detection Voltage (Vcha).

In the normal charging condition, the voltage between V_M and V_{SS} to which when V2 decreases, The charging control FET turns off, V_{S1} is the threshold of a diode, is the charge overcurrent detection voltage. It has the same value as the Charger Detection Voltage (Vcha).

(5) 0V battery charge starting charger voltage (Test circuit 6)

Set V1=V2=0V, increase V2 gradually until I_{V2} =10mA. The voltage between VDD and VM is the 0V battery charge starting charger voltage.

(6) Normal operation current consumption and power down current consumption (Test circuit 2)

Set V1=3.9V and V2=0V under normal condition, the current I_{DD} flowing through V_{DD} pin is the normal operation consumption current (I_{DD}).

Set V1=3.9V and V2=0V, let IC work in normal condition, set V1 from 3.9V to 2.0V, then set V2=2.0V under overdischarge condition, the current I_{DD} flowing through V_{DD} pin is the power down current consumption ($I_{STANDBY}$).

(7) Overcharge detection (release) delay time and overdischarge detection (release) delay time (Test circuit 3)

If V1 increases to be Vdet1 or over Vdet1 and keeps the condition for some time, the charging control FET will turn off, Vs₁ is the threshold of a diode, The time is called overcharge detection delay time. It is used to judge whether overcharge happens indeed.



If V1 decreases from Vdet1 or over Vdet1 to below Vrel1, the charging control FET will turn on, $Vs_1=0V$. The difference between this time and Treset is called overcharge release delay time.

If V1 decreases to be Vdet2 or below Vdet2 and keeps the condition for some time, the discharging control FET will turn off, Vs_1 =V1. The time is called overdischarge detection delay time. It is used to judge whether overdischarge happens indeed.

If V1 increases from Vdet2 or below Vdet2 to over Vrel2 and keeps the condition for some time, the discharging control FET will turn on, $Vs_1=0V$. The time is called overdischarge release delay time.

(8) Discharge overcurrent detection delay time and short circuit detection delay time (Test circuit 4)

If V2 increases to be Vdet3 or over Vdet3 and keeps the condition for some time, the discharging control FET will turn off, Vs₁=V1. The time is called Discharge overcurrent Delay Time. It is used to judge whether Discharge overcurrent happens indeed.

If V2 increases to be Vdet4 or over Vdet4 and keeps the condition for some time, the discharging control FET will turn off, Vs₁=V1. The time is called Discharge Overcurrent 2 Delay Time. It is used to judge whether Discharge Overcurrent 2 happens indeed.

If V2 increases to be Vshort or over Vshort and keeps the condition for some time, the discharging control FET will turn off, $Vs_1=V1$. The time is called short circuit delay time. It is used to judge whether short circuit happens indeed.

(9) Internal resistance VM -VDD and VM -VSS (Test circuit 4)

Set V1=2.0 V, V2=0 V, V1/I_{VM} is the internal resistance R_{VMD}.

Set V1=3.3 V, V2=1 V, V2/ I_{VM} is the internal resistance R_{VMS} .

(10) Charger Overvoltage detection voltage and overvoltage release voltage (Test circuit 5)

Set V1= V2=3.60V

- 1. Set V2=6.00V, delay 2ms, test VS1, if it is "H"*2, stop test; if it is "L"*3, set V2=3.60V, delay 10ms.
- 2. Set V2=6.10V, delay 2ms, test VS1, if it is "H", stop test; if it is "L",set V2=3.60V, delay 10ms.
- 3. Set V2=6.20V, delay 2ms, test VS1, if it is "H", stop test; if it is "L", set V2=3.60V, delay 10ms.

Increase V2 with step 0.10V ,until Vco changes from "L" to "H". Then the V2 is the Charger Overvoltage detection voltage(Vdet5).

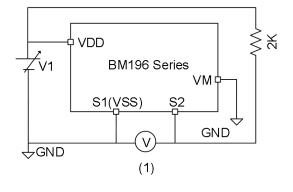
Set V1= V2=3.60V

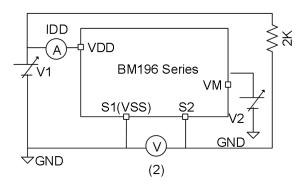
- 1. Set V2= Vdet5 delay 2ms
 - Set V2= V2 '= Vdet5-0.10V delay 2ms, test VS1 if it is "L", stop test; if it is "H", set V2=3.60V, delay 10ms.
- 2. Set V2= V2 'delay 2ms
 - Set V2= V2 "= V2 '-0.10V delay 2ms, test VS1 if it is "L", stop test; if it is "H",set V2=3.60V, delay 10ms.
- 3. Set V2= V2 " delay 2ms
 - Set V2= V2 "- V2"-0.10V delay 2ms, test VS1 if it is "L", stop test; if it is "H", set V2=3.60V, delay 10ms.

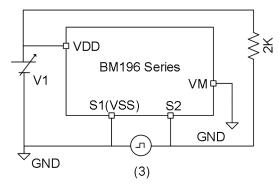
Decrease V2 with step 0.10V ,until VS1 changes from "H" to "L". Then the V2 is the Charger Overvoltage Release Voltage (Vrel5).

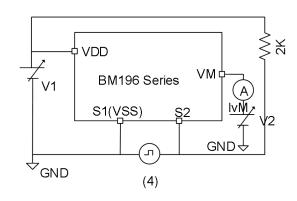
Note: *2 "H" - VS1 > 0.200V, *3 "L" - -0.050V < VS1 < 0.050V

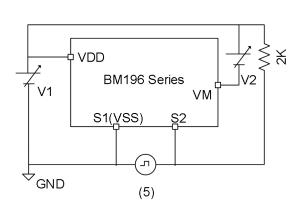


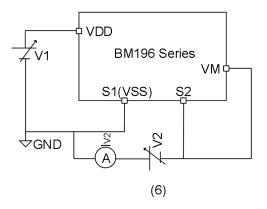








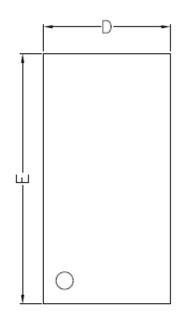


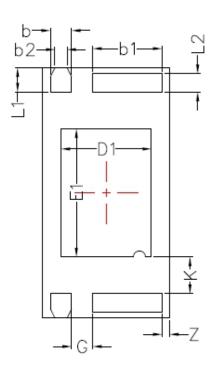


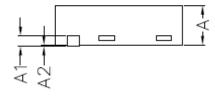


Package Outline

DFN2.1*4.1-4L







NOTE:

Unit: mm.

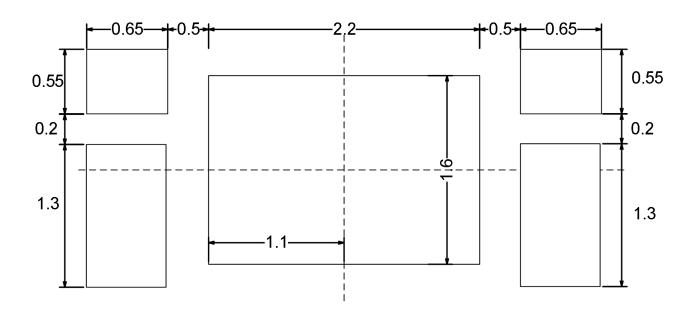
	MIN	NOM	MAX
Α	0.60	0.65	0.70
A1		0.15R E F	-
A2	0.00	0.02	0.05
D	2.05	2.10	2.15
E	4.05	4.10	4.15
D1	1.45	1.50	1.55
E1	2.05	2.10	2.15
L1	0.35	0.40	0.45
L2	0.25	0.30	0.35
b	0.25	0.35	0.35
b1	1.10	1.15	1.20
b2		0.20RE	-
G	0.30	0.35	0.40
K	0.55	0.60	0.65
Z	0.075	0.125	0.175



Packing

MBB packing.7" reel: 3000 pcs per reel.

PCB Layout (mm)





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